

# Low-Voltage CMOS Octal Transceiver/Registered Transceiver With Dual Enable With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX652 is a high performance, non-inverting octal transceiver/registered transceiver operating from a 2.7 to 3.6V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A  $V_I$  specification of 5.5V allows MC74LCX652 inputs to be safely driven from 5V devices. The MC74LCX652 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes from a LOW-to-HIGH logic level. Two Output Enable pins (OEBA, OEAB) are provided to control the transceiver outputs. In the transceiver mode, data present at the high impedance port may be stored in either the A or the B register or in both. The select controls (SBA, SAB) can multiplex stored and real-time (transparent mode) data. In the isolation mode (both outputs disabled), A data may be stored in the B register or B data may be stored in the A register. When in the real-time mode, it is possible to store data without using the internal registers by simultaneously enabling OEAB and OEBA. In this configuration, each output reinforces its input (data retention is not guaranteed in this mode).

- Designed for 2.7 to 3.6V  $V_{CC}$  Operation
- 5V Tolerant — Interface Capability With 5V TTL Logic
- Supports Live Insertion and Withdrawal
- I<sub>OFF</sub> Specification Guarantees High Impedance When  $V_{CC} = 0V$
- LVTTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10 $\mu$ A) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

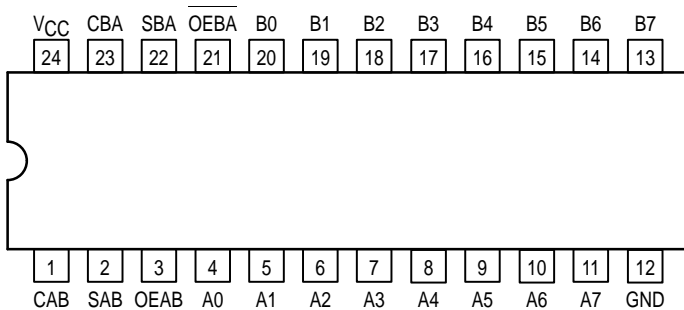
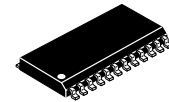


Figure 1. 24-Lead Pinout (Top View)

**MC74LCX652**

**LCX**

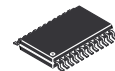
**LOW-VOLTAGE CMOS  
OCTAL TRANSCEIVER/  
REGISTERED TRANSCEIVER  
WITH DUAL ENABLE**



**DW SUFFIX**  
24-LEAD PLASTIC SOIC PACKAGE  
CASE 751E-04



**SD SUFFIX**  
24-LEAD PLASTIC SSOP PACKAGE  
CASE 940D-03



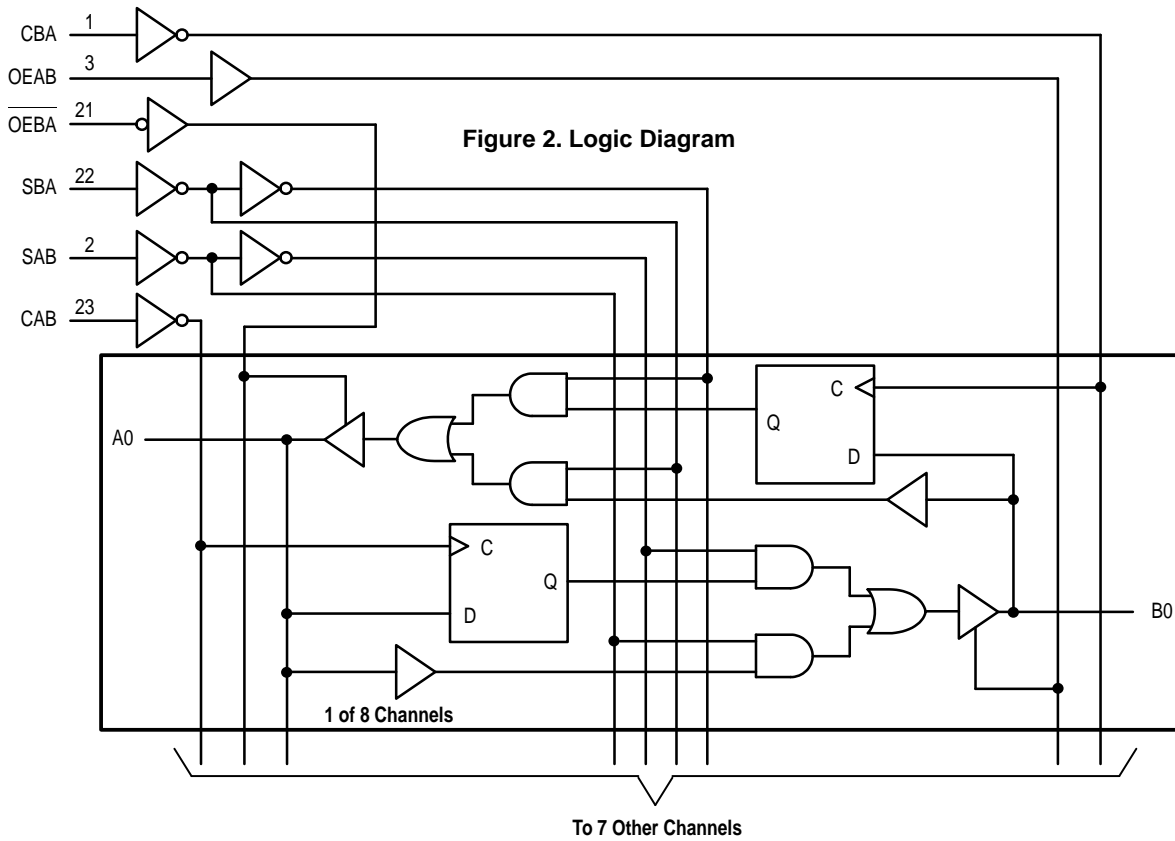
**DT SUFFIX**  
24-LEAD PLASTIC TSSOP PACKAGE  
CASE 948H-01

**PIN NAMES**

Pins	Function
A0–A7	Side A Inputs/Outputs
B0–B7	Side B Inputs/Outputs
CAB, CBA	Clock Pulse Inputs
SAB, SBA	Select Control Inputs
OEBA, OEAB	Output Enable Inputs



MC74LCX652



FUNCTION TABLE

Inputs						Data Ports		Operating Mode
OEAB	OEBA	CAB	CBA	SAB	SBA	An	Bn	
L	H					<b>Input</b>	<b>Input</b>	
		↑	↑	X	X	X	X	Isolation, Hold Storage
		↑	↑	X	X	I h	I h	Store A and/or B Data
H	H					<b>Input</b>	<b>Output</b>	
		↑	X*	L	X	L H	L H	Real Time A Data to B Bus
				H	X	X	QA	Stored A Data to B Bus
		↑	X*	L	X	I h	L H	Real Time A Data to B Bus; Store A Data
				H	X	L H	QA QA	Clock A Data to B Bus; Store A Data
L	L					<b>Output</b>	<b>Input</b>	
		X*	↑	X	L	L H	L H	Real Time B Data to A Bus
				X	H	QB	X	Stored B Data to A Bus
		X*	↑	X	L	L H	I h	Real Time B Data to A Bus; Store B Data
				X	H	QB QB	L H	Clock B Data to A Bus; Store B Data
H	L					<b>Output</b>	<b>Output</b>	
		↑	↑	H	H	QB	QA	Stored A Data to B Bus, Stored B Data to A Bus

H = High Voltage Level; h = High Voltage Level One Setup Time Prior to the Low-to-High Clock Transition; L = Low Voltage Level; I = Low Voltage Level One Setup Time Prior to the Low-to-High Clock Transition; X = Don't Care; ↑ = Low-to-High Clock Transition; ↓ = NOT Low-to-High Clock Transition; QA = A input storage register; QB = B input storage register; \* = The clocks are not internally gated with either the Output Enables or the Source Inputs. Therefore, data at the A or B ports may be clocked into the storage registers, at any time. For I<sub>CC</sub> reasons, Do Not Float Inputs.

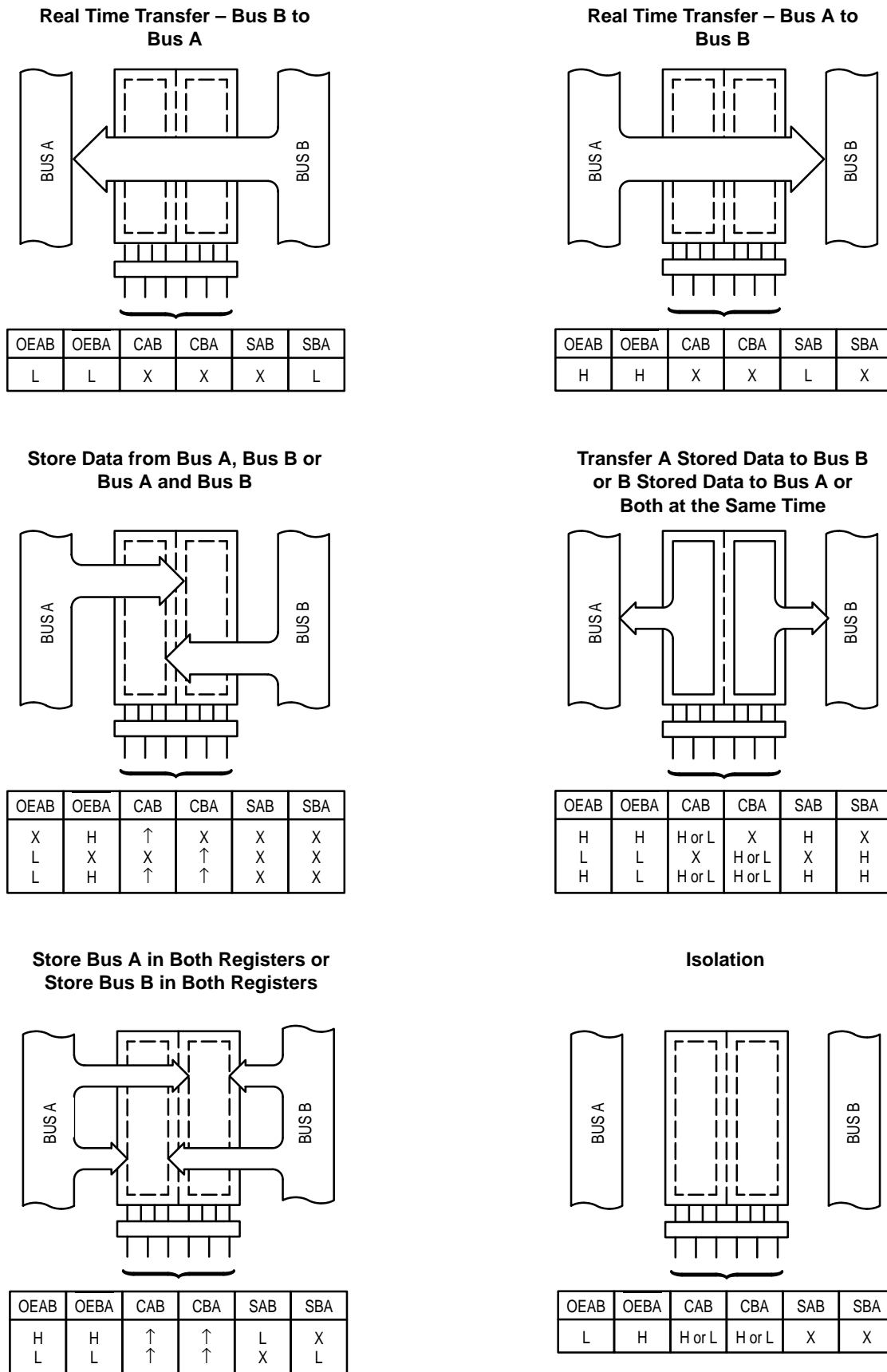


Figure 3. Bus Applications

**ABSOLUTE MAXIMUM RATINGS\***

Symbol	Parameter	Value	Condition	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0		V
V <sub>I</sub>	DC Input Voltage	-0.5 ≤ V <sub>I</sub> ≤ +7.0		V
V <sub>O</sub>	DC Output Voltage	-0.5 ≤ V <sub>O</sub> ≤ +7.0	Output in 3-State	V
		-0.5 ≤ V <sub>O</sub> ≤ V <sub>CC</sub> + 0.5	Note 1.	V
I <sub>IK</sub>	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA
I <sub>OK</sub>	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA
		+50	V <sub>O</sub> > V <sub>CC</sub>	mA
I <sub>O</sub>	DC Output Source/Sink Current	±50		mA
I <sub>CC</sub>	DC Supply Current Per Supply Pin	±100		mA
I <sub>GND</sub>	DC Ground Current Per Ground Pin	±100		mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150		°C

\* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

1. Output in HIGH or LOW State. I<sub>O</sub> absolute maximum rating must be observed.

**RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Typ	Max	Unit	
V <sub>CC</sub>	Supply Voltage	Operating	2.0	3.3	3.6	V
		Data Retention Only	1.5	3.3	3.6	
V <sub>I</sub>	Input Voltage	0		5.5	V	
V <sub>O</sub>	Output Voltage (HIGH or LOW State) (3-State)	0		V <sub>CC</sub>	V	
		0		5.5		
I <sub>OH</sub>	HIGH Level Output Current, V <sub>CC</sub> = 3.0V – 3.6V			-24	mA	
I <sub>OL</sub>	LOW Level Output Current, V <sub>CC</sub> = 3.0V – 3.6V			24	mA	
I <sub>OH</sub>	HIGH Level Output Current, V <sub>CC</sub> = 2.7V – 3.0V			-12	mA	
I <sub>OL</sub>	LOW Level Output Current, V <sub>CC</sub> = 2.7V – 3.0V			12	mA	
T <sub>A</sub>	Operating Free-Air Temperature	-40		+85	°C	
Δt/ΔV	Input Transition Rise or Fall Rate, V <sub>IN</sub> from 0.8V to 2.0V, V <sub>CC</sub> = 3.0V	0		10	ns/V	

**DC ELECTRICAL CHARACTERISTICS**

Symbol	Characteristic	Condition	T <sub>A</sub> = -40°C to +85°C		Unit
			Min	Max	
V <sub>IH</sub>	HIGH Level Input Voltage (Note 2.)	2.7V ≤ V <sub>CC</sub> ≤ 3.6V	2.0		V
V <sub>IL</sub>	LOW Level Input Voltage (Note 2.)	2.7V ≤ V <sub>CC</sub> ≤ 3.6V		0.8	V
V <sub>OH</sub>	HIGH Level Output Voltage	2.7V ≤ V <sub>CC</sub> ≤ 3.6V; I <sub>OH</sub> = -100μA	V <sub>CC</sub> - 0.2		V
		V <sub>CC</sub> = 2.7V; I <sub>OH</sub> = -12mA	2.2		
		V <sub>CC</sub> = 3.0V; I <sub>OH</sub> = -18mA	2.4		
		V <sub>CC</sub> = 3.0V; I <sub>OH</sub> = -24mA	2.2		
V <sub>OL</sub>	LOW Level Output Voltage	2.7V ≤ V <sub>CC</sub> ≤ 3.6V; I <sub>OL</sub> = 100μA		0.2	V
		V <sub>CC</sub> = 2.7V; I <sub>OL</sub> = 12mA		0.4	
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 16mA		0.4	
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 24mA		0.55	

2. These values of V<sub>I</sub> are used to test DC electrical characteristics only.

**DC ELECTRICAL CHARACTERISTICS** (continued)

Symbol	Characteristic	Condition	T <sub>A</sub> = -40°C to +85°C		Unit
			Min	Max	
I <sub>I</sub>	Input Leakage Current	2.7V ≤ V <sub>CC</sub> ≤ 3.6V; 0V ≤ V <sub>I</sub> ≤ 5.5V		±5.0	μA
I <sub>OZ</sub>	3-State Output Current	2.7 ≤ V <sub>CC</sub> ≤ 3.6V; 0V ≤ V <sub>O</sub> ≤ 5.5V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>		±5.0	μA
I <sub>OFF</sub>	Power-Off Leakage Current	V <sub>CC</sub> = 0V; V <sub>I</sub> or V <sub>O</sub> = 5.5V		10	μA
I <sub>CC</sub>	Quiescent Supply Current	2.7 ≤ V <sub>CC</sub> ≤ 3.6V; V <sub>I</sub> = GND or V <sub>CC</sub>		10	μA
		2.7 ≤ V <sub>CC</sub> ≤ 3.6V; 3.6 ≤ V <sub>I</sub> or V <sub>O</sub> ≤ 5.5V		±10	μA
ΔI <sub>CC</sub>	Increase in I <sub>CC</sub> per Input	2.7 ≤ V <sub>CC</sub> ≤ 3.6V; V <sub>IH</sub> = V <sub>CC</sub> - 0.6V		500	μA

**AC CHARACTERISTICS** (t<sub>R</sub> = t<sub>F</sub> = 2.5ns; C<sub>L</sub> = 50pF; R<sub>L</sub> = 500Ω)

Symbol	Parameter	Waveform	Limits				Unit
			T <sub>A</sub> = -40°C to +85°C				
			V <sub>CC</sub> = 3.0V to 3.6V		V <sub>CC</sub> = 2.7V		
			Min	Max	Min	Max	
f <sub>max</sub>	Clock Pulse Frequency	3	150				MHz
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Input to Output	1	1.5	7.0	1.5	8.0	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Clock to Output	3	1.5	8.5	1.5	9.5	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Select to Output	1	1.5	8.5	1.5	9.5	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time to High and Low Level	2	1.5	8.5	1.5	9.5	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time From High and Low Level	2	1.5	8.5	1.5	9.5	ns
t <sub>s</sub>	Setup Time, HIGH or LOW Data to Clock	3	2.5		2.5		ns
t <sub>h</sub>	Hold Time, HIGH or LOW Data to Clock	3	1.5		1.5		ns
t <sub>w</sub>	Clock Pulse Width, HIGH or LOW	3	3.3		3.3		ns
t <sub>OSHL</sub> t <sub>OSLH</sub>	Output-to-Output Skew (Note 3.)			1.0			ns

3. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.

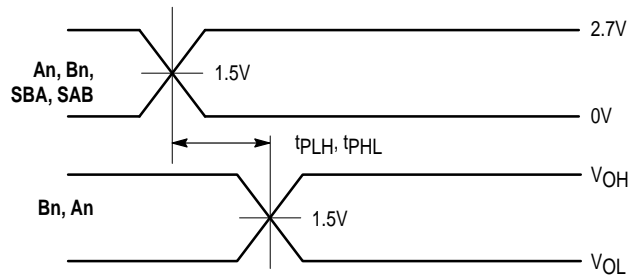
**DYNAMIC SWITCHING CHARACTERISTICS**

Symbol	Characteristic	Condition	T <sub>A</sub> = +25°C			Unit
			Min	Typ	Max	
V <sub>OLP</sub>	Dynamic LOW Peak Voltage (Note 4.)	V <sub>CC</sub> = 3.3V, C <sub>L</sub> = 50pF, V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V		0.8		V
V <sub>OLV</sub>	Dynamic LOW Valley Voltage (Note 4.)	V <sub>CC</sub> = 3.3V, C <sub>L</sub> = 50pF, V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V		0.8		V

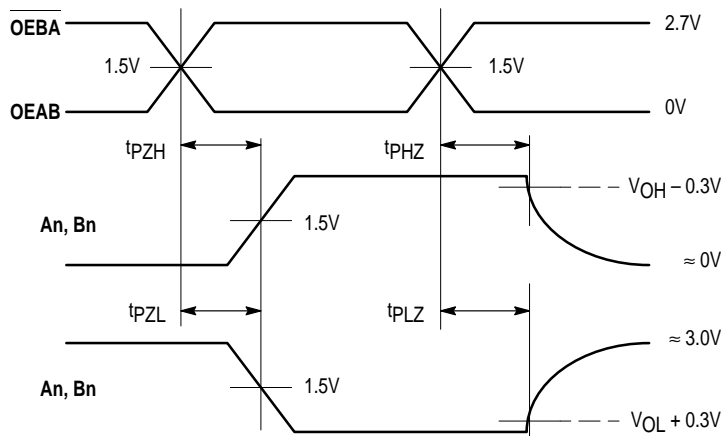
4. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state. The LCX652 is characterized with 7 outputs switching with 1 output held LOW.

**CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 3.3V, V <sub>I</sub> = 0V or V <sub>CC</sub>	7	pF
C <sub>I/O</sub>	Input/Output Capacitance	V <sub>CC</sub> = 3.3V, V <sub>I</sub> = 0V or V <sub>CC</sub>	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	10MHz, V <sub>CC</sub> = 3.3V, V <sub>I</sub> = 0V or V <sub>CC</sub>	25	pF

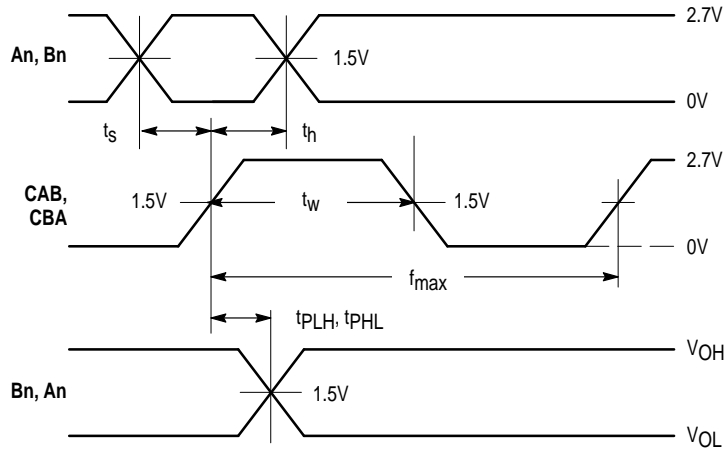


**WAVEFORM 1 – SAB to B and SBA to A, An to Bn PROPAGATION DELAYS**  
 $t_R = t_F = 2.5\text{ns}$ , 10% to 90%;  $f = 1\text{MHz}$ ;  $t_W = 500\text{ns}$



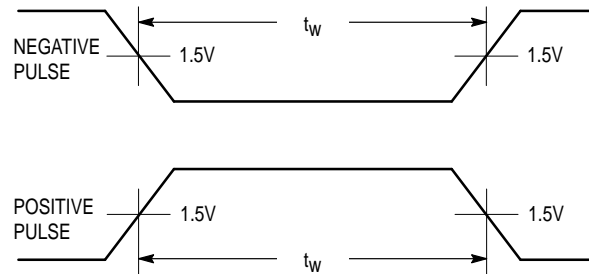
**WAVEFORM 2 – OEBA/OEAB to An/Bn OUTPUT ENABLE AND DISABLE TIMES**  
 $t_R = t_F = 2.5\text{ns}$ , 10% to 90%;  $f = 1\text{MHz}$ ;  $t_W = 500\text{ns}$

**Figure 4. AC Waveforms**



**WAVEFORM 3 – CLOCK to Bn/An PROPAGATION DELAYS, CLOCK MINIMUM PULSE WIDTH, An/Bn to CLOCK SETUP AND HOLD TIMES**

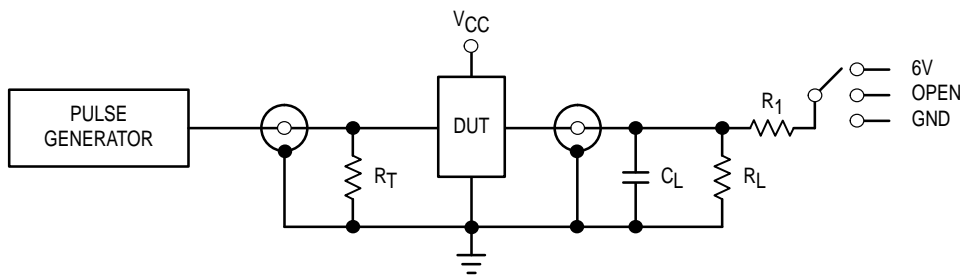
$t_R = t_F = 2.5ns$ , 10% to 90%;  $f = 1MHz$ ;  $t_W = 500ns$  except when noted



**WAVEFORM 4 – INPUT PULSE DEFINITION**

$t_R = t_F = 2.5ns$ , 10% to 90% of 0V to 2.7V

**Figure 5. AC Waveforms (continued)**



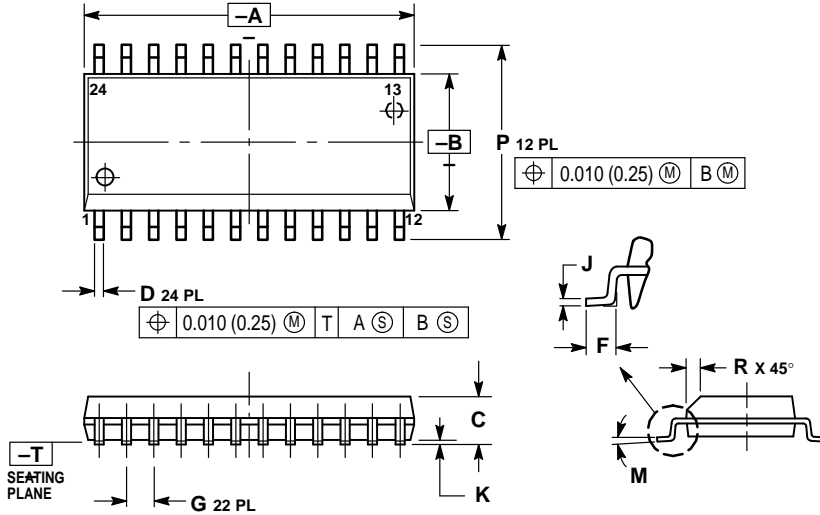
TEST	SWITCH
$t_{PLH}$ , $t_{PHL}$	Open
$t_{PZL}$ , $t_{PLZ}$	6V
Open Collector/Drain $t_{PLH}$ and $t_{PHL}$	6V
$t_{PZH}$ , $t_{PHZ}$	GND

$C_L = 50pF$  or equivalent (Includes jig and probe capacitance)  
 $R_L = R_1 = 500\Omega$  or equivalent  
 $R_T = Z_{OUT}$  of pulse generator (typically  $50\Omega$ )

**Figure 6. Test Circuit**

OUTLINE DIMENSIONS

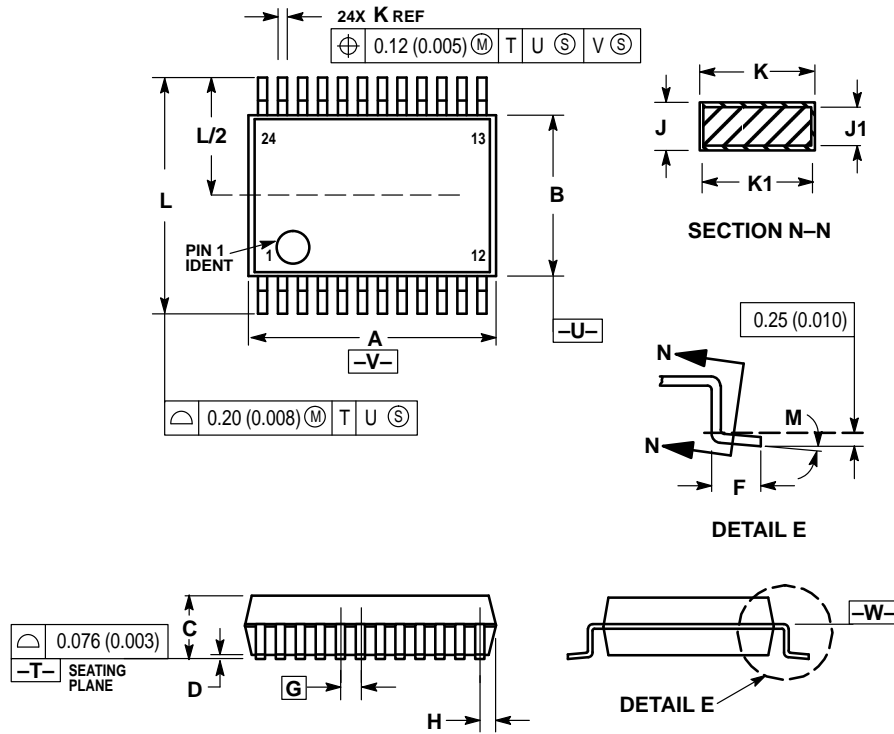
DW SUFFIX  
PLASTIC SOIC PACKAGE  
CASE 751E-04  
ISSUE E



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	15.25	15.54	0.601	0.612
B	7.40	7.60	0.292	0.299
C	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.41	0.90	0.016	0.035
G	1.27 BSC		0.050 BSC	
J	0.23	0.32	0.009	0.013
K	0.13	0.29	0.005	0.011
M	0°	8°	0°	8°
P	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

SD SUFFIX  
PLASTIC SSOP PACKAGE  
CASE 940D-03  
ISSUE B



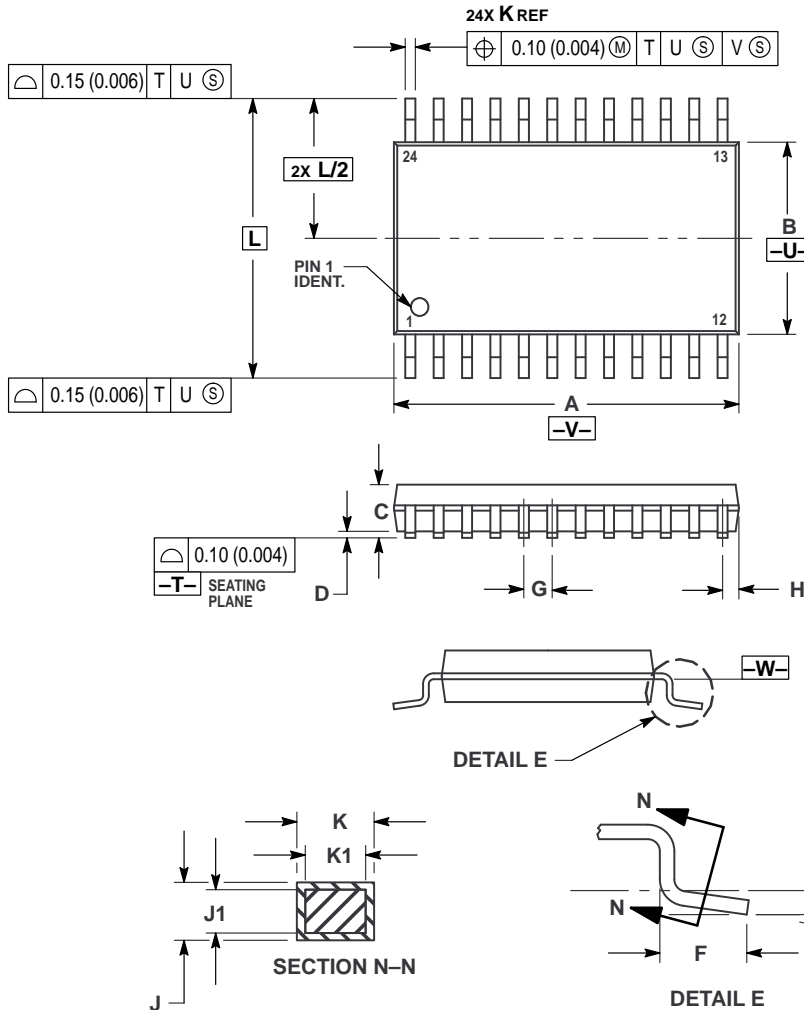
- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION/INTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF K DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR INTRUSION SHALL NOT REDUCE DIMENSION K BY MORE THAN 0.07 (0.002) AT LEAST MATERIAL CONDITION.
  6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
  7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.07	8.33	0.317	0.328
B	5.20	5.38	0.205	0.212
C	1.73	1.99	0.068	0.078
D	0.05	0.21	0.002	0.008
F	0.63	0.95	0.024	0.037
G	0.65 BSC		0.026 BSC	
H	0.44	0.60	0.017	0.024
J	0.09	0.20	0.003	0.008
J1	0.09	0.16	0.003	0.006
K	0.25	0.38	0.010	0.015
K1	0.25	0.33	0.010	0.013
L	7.65	7.90	0.301	0.311
M	0°	8°	0°	8°



OUTLINE DIMENSIONS

DT SUFFIX  
PLASTIC TSSOP PACKAGE  
CASE 948H-01  
ISSUE O



- NOTES:
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  - 2 CONTROLLING DIMENSION: MILLIMETER.
  - 3 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  - 4 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
  - 5 DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
  - 6 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
  - 7 DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	7.70	7.90	0.303	0.311
B	4.30	4.50	0.169	0.177
C	—	1.20	—	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

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